Quad MECL-to-TTL Translator

The MC10H125 is a quad translator for interfacing data and control signals between the MECL section and saturated logic section of digital systems. The 10H part is a functional/pinout duplication of the standard MECL 10K family part, with 100% improvement in propagation delay, and no increase in power-supply current.

Outputs of unused translators will go to low state when their inputs are left open.

- Propagation Delay, 2.5 ns Typical
- Voltage Compensated
- Improved Noise Margin 150 mV (Over Operating Voltage and Temperature Range)
- MECL 10K-Compatible



ON Semiconductor[®]

http://onsemi.com



YY = Year

WW = Work Week

ORDERING INFORMATION

Device	Package	Shipping
MC10H125L	CDIP	25 Units/Rail
MC10H125P	PDIP-16	25 Units/Rail
MC10H125FN	PLCC-20	46 Units/Rail
MC10H125M	EIAJ-16	50 Units/Rail
MC10H125MEL	EIAJ-16	2000 Units/Reel

LOGIC DIAGRAM



 $^{*}V_{BB}$ to be used to supply bias to the MC10H125 only and bypassed (when used) with 0.01 μF to 0.1 μF capacitor to ground (0 V). V_{BB} can source < 1.0 mA.



Pin assignment is for Dual-in-Line Package. For PLCC pin assignment, see the Pin Conversion Tables.

DIP CONVERSION TABLES

16-Pin DIL to 20-Pin PLCC

16 PIN DIL	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	
20 PIN PLCC	2	3	4	5	7	8	9	10	12	13	14	15	17	18	19	20	

20-Pin DIL to 20-Pin PLCC

20 PIN DIL	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19	20
20 PIN PLCC	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19	20

MAXIMUM RATINGS

Symbol	Characteristic	Rating	Unit
V _{EE}	Power Supply ($V_{CC} = 5.0 \text{ V}$)	-8.0 to 0	Vdc
V _{CC}	Power Supply (V _{EE} = -5.2 V)	0 to +7.0	Vdc
VI	Input Voltage ($V_{CC} = 5.0 \text{ V}$)	0 to V _{EE}	Vdc
T _A	Operating Temperature Range	0 to +75	°C
T _{stg}	Storage Temperature Range - Plas - Ceran	tic -55 to +150 nic -55 to +165	°C ℃

ELECTRICAL CHARACTERISTICS (V_{EE} = -5.2 V +5%; V_{CC} = 5.0 V + 5.0 %) (Note 2)

		(°	2	5°			
Symbol	Characteristic	Min	Max	Min	Max	Min	Max	Unit
Ι _Ε	Negative Power Supply Drain Current	-	44	-	40	-	44	mA
I _{CCH}	Positive Power Supply	-	63	-	63	-	63	mA
I _{CCL}	Drain Current	-	40	-	40	-	40	mA
l _{inH}	Input Current	-	225	-	145	-	145	μΑ
I _{CBO}	Input Leakage Current	-	1.5	-	1.0	-	1.0	μΑ
V _{OH}	High Output Voltage I _{OH} = -1.0 mA	2.5	-	2.5	-	2.5	-	Vdc
V _{OL}	Low Output Voltage I _{OL} = +20 mA	-	0.5	-	0.5	-	0.5	Vdc
V _{IH}	High Input Voltage (Note 1)	-1.17	-0.84	-1.13	-0.81	-1.07	-0.735	Vdc
V _{IL}	Low Input Voltage (Note 1)	-1.95	-1.48	-1.95	-1.48	-1.95	-1.45	Vdc
I _{OS}	Short Circuit Current	60	150	60	150	50	150	mA
V _{BB}	Reference Voltage	-1.38	-1.27	-1.35	-1.25	-1.31	-1.19	Vdc
V _{CMR}	Common Mode Range (Note 3)	-	-	-2.85 1	to +0.3			V
		ТурісаІ						
V _{PP}	Input Sensitivity (Note 4)				150			mV

AC PARAMETERS

		0 °		2	5°	7		
Symbol	Characteristic	Min	Мах	Min	Max	Min	Max	Unit
t _{pd}	Propagation Delay	0.8	3.3	0.85	3.35	0.9	3.4	ns
tr	Rise Time (Note 5)	0.3	1.2	0.3	1.2	0.3	1.2	ns
t _f	Fall Time (Note 5)	0.3	1.2	0.3	1.2	0.3	1.2	ns

 When V_{BB} is used as the reference voltage.
 Each MECL 10H series circuit has been designed to meet the specifications shown in the test table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 linear fpm is maintained.

3. Differential input not to exceed 1.0 Vdc. 4. 150 mV_{p-p} differential input required to obtain full logic swing on output. 5. Output Voltage = 1.0 V to 2.0 V. R_L = 500 Ω to GND and C_L = 25 pF to GND. Refer to Figure 1.



Figure 1. TTL Output Loading Used for Device Evaluation

APPLICATION INFORMATION

The MC10H125 incorporates differential inputs and Schottky TTL "totem pole" outputs. Differential inputs allow for use as an inverting/non-inverting translator or as a differential line receiver. The V_{BB} reference voltage is available on Pin 1 for use in single-ended input biasing. The outputs of the MC10H125 go to a low-logic level whenever the inputs are left floating, and a high-logic output level is achieved with a minimum input level of 150 mV_{p-p}. An advantage of this device is that MECL-level information can be received, via balanced twisted pair lines, in the TTL equipment. This isolates the MECL-logic from the noisy TTL environment. Power supply requirements are ground, +5.0 volts and -5.2 volts.

PACKAGE DIMENSIONS









- NOTES: 1. DATUMS -L-, -M-, AND -N- DETERMINED WHERE TOP OF LEAD SHOULDER EXITS PLASTIC BODY AT MOLD PARTING LINE.
- DIMENSION G1, TRUE POSITION TO BE MEASURED AT DATUM -T-, SEATING PLANE.
 DIMENSIONS R AND U DO NOT INCLUDE MOLD
- DIMENSIONS HAND O DO NOT INCLODE MOLD FLASH. ALLOWABLE MOLD FLASH IS 0.010 (0.250) PER SIDE.
 DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: INCH.
 THE PACKAGE TOP MAY BE SMALLER THAN THE DID//CONTROL/UP TO GOLD (0.050)

- PACKAGE OF WAY DE SWALLER THAY THE PACKAGE BOTTOM BY UP TO 0.012 (0.300). DIMENSIONS R AND U ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY EXCLUSIVE OF MOLD FLASH, TIE BAR BURRS,
- EXCLUSIVE OF MOLD FLASH, TIE BAR BURRS, GATE BURRS AND INTERLEAD FLASH, BUT INCLUDING ANY MISMATCH BETWEEN THE TOP AND BOTTOM OF THE PLASTIC BODY. 7. DIMENSION H DOES NOT INCLUDE DAMBAR PROTRUSION OR INTRUSION. THE DAMBAR PROTRUSION TO BE GREATER THAN 0.037 (0.940). THE DAMBAR INTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE SMALLER THAN 0.025 (0.635). (0.635).

	INC	HES	MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.385	0.395	9.78	10.03
В	0.385	0.395	9.78	10.03
C	0.165	0.180	4.20	4.57
E	0.090	0.110	2.29	2.79
F	0.013	0.019	0.33	0.48
G	0.050	BSC	1.27	BSC
Н	0.026	0.032	0.66	0.81
J	0.020		0.51	
K	0.025		0.64	
R	0.350	0.356	8.89	9.04
U	0.350	0.356	8.89	9.04
۷	0.042	0.048	1.07	1.21
W	0.042	0.048	1.07	1.21
X	0.042	0.056	1.07	1.42
Y		0.020		0.50
Z	2 °	10 °	2 °	10 °
G1	0.310	0.330	7.88	8.38
K1	0.040		1.02	

CDIP CASE 620A-01 ISSUE O





	16X J –							
€	0.25 (0.010) 🕅	Т	В					





- NOTES: 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: INCH. 3. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL 4. DIMENSION F MAY NARROW TO 0.76 (0.030) WHERE THE LEAD ENTERS THE CERAMIC BODY.

5

PDIP-16 **P SUFFIX** PLASTIC DIP PACKAGE CASE 648-08 ISSUE R



NOTES:

DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: INCH.
 DIMENSION LTO CENTER OF LEADS WHEN FORMER DATALLES.

FORMED PARALLEL. DIMENSION B DOES NOT INCLUDE MOLD FLASH. 4. 5. ROUNDED CORNERS OPTIONAL.

	INC	HES	MILLIM	ETERS			
DIM	MIN	MAX	MIN	MAX			
Α	0.740	0.770	18.80	19.55			
В	0.250	0.270	6.35	6.85			
С	0.145	0.175	3.69	4.44			
D	0.015	0.021	0.39	0.53			
F	0.040	0.70	1.02	1.77			
G	0.100	BSC	2.54 BSC				
н	0.050	BSC	1.27	BSC			
J	0.008	0.015	0.21	0.38			
K	0.110	0.130	2.80	3.30			
L	0.295	0.305	7.50	7.74			
M	0°	10 °	0 °	10 °			
S	0.020	0.040	0.51	1 01			

STYLE 1:

N 1.	CATHODE
2.	CATHODE
3.	CATHODE
4.	CATHODE
5.	CATHODE
6.	CATHODE
7.	CATHODE
8.	CATHODE
9.	ANODE
10.	ANODE
11.	ANODE
12.	ANODE
13.	ANODE
14.	ANODE
15.	ANODE
16.	ANODE

EIAJ-16 **M SUFFIX 16 PIN PLASTIC EIAJ PACKAGE** CASE966-01 **ISSUE O**









- NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: MILLIMETER.
- DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006)
- PER SIDE. 4.

TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY. THE LEAD WIDTH DIMENSION (b) DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE 5. INCLODE DAMBAR PROTINGSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE COB (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018).

	MILLIN	IETERS	INC	HES						
DIM	MIN	MAX	MIN	MAX						
Α		2.05		0.081						
A ₁	0.05	0.20	0.002	0.008						
b	0.35	0.50	0.014	0.020						
C	0.18	0.27	0.007	0.011						
D	9.90	10.50	0.390	0.413						
Ε	5.10	5.45	0.201	0.215						
е	1.27	BSC	0.050 BSC							
HE	7.40	8.20	0.291	0.323						
L	0.50	0.85	0.020	0.033						
LE	1.10	1.50	0.043	0.059						
М	0 °	10 °	0 °	10 °						
Q1	0.70	0.90	0.028	0.035						
Z		0.78		0.031						

ON Semiconductor and **W** are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death wits such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer.

PUBLICATION ORDERING INFORMATION

Literature Fulfillment:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA

Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: ONlit@hibbertco.com

N. American Technical Support: 800-282-9855 Toll Free USA/Canada

JAPAN: ON Semiconductor, Japan Customer Focus Center 2-9-1 Kamimeguro, Meguro-ku, Tokyo, Japan 153-0051 Phone: 81-3-5773-3850

ON Semiconductor Website: http://onsemi.com

For additional information, please contact your local Sales Representative.

Copyright © Each Manufacturing Company.

All Datasheets cannot be modified without permission.

This datasheet has been download from :

www.AllDataSheet.com

100% Free DataSheet Search Site.

Free Download.

No Register.

Fast Search System.

www.AllDataSheet.com